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# March 2004



# AS7C31024B

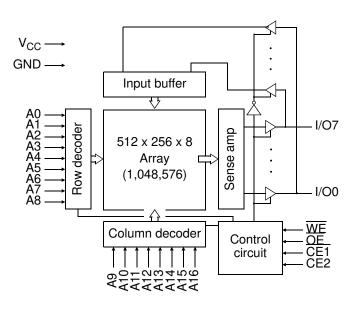
#### Features

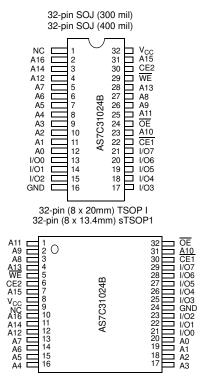
- Industrial and commercial temperatures
- Organization: 131,072 words x 8 bits
- High speed
  - 10/12/15/20 ns address access time
  - 5, 6, 7, 8 ns output enable access time
- Low power consumption: ACTIVE - 252 mW / max @ 10 ns
- Low power consumption: STANDBY - 18 mW / max CMOS
- 6T 0.18u CMOS technology

- Easy memory expansion with  $\overline{CE1}$ , CE2,  $\overline{OE}$  inputs
- TTL/LVTTL-compatible, three-state I/O
- 32-pin JEDEC standard packages
  - 300 mil SOJ
  - 400 mil SOJ
- 8 × 20mm TSOP 1
- 8 x 13.4mm sTSOP 1
- ESD protection  $\geq 2000$  volts
- Latch-up current  $\ge 200 \text{ mA}$

#### **Pin arrangement**

# Logic block diagram





#### **Selection guide**

	-10	-12	-15	-20	Unit
Maximum address access time	10	12	15	20	ns
Maximum output enable access time	5	6	7	8	ns
Maximum operating current	70	65	60	55	mA
Maximum CMOS standby current	5	5	5	5	mA

#### **Functional description**

The AS7C31024B is a high performance CMOS 1,048,576-bit Static Random Access Memory (SRAM) device organized as 131,072 words x 8 bits. It is designed for memory applications where fast data access, low power, and simple interfacing are desired.

Equal address access and cycle times ( $t_{AA}$ ,  $t_{RC}$ ,  $t_{WC}$ ) of 10/12/15/20 ns with output enable access times ( $t_{OE}$ ) of 5, 6, 7, 8 ns are ideal for high performance applications. Active high and low chip enables ( $\overline{CE1}$ , CE2) permit easy memory expansion with multiple-bank systems.

When  $\overline{\text{CE1}}$  is high or CE2 is low, the device enters standby mode. If inputs are still toggling, the device will consume I<sub>SB</sub> power. If the bus is static, then full standby power is reached (I<sub>SB1</sub>). For example, the AS7C31024B is guaranteed not to exceed 18 mW under nominal full standby conditions.

A write cycle is accomplished by asserting write enable ( $\overline{WE}$ ) and both chip enables ( $\overline{CE1}$ , CE2). Data on the input pins I/O0 through I/O7 is written on the rising edge of  $\overline{WE}$  (write cycle 1) or the active-to-inactive edge of  $\overline{CE1}$  or CE2 (write cycle 2). To avoid bus contention, external devices should drive I/O pins only after outputs have been disabled with output enable ( $\overline{OE}$ ) or write enable ( $\overline{WE}$ ).

A read cycle is accomplished by asserting output enable ( $\overline{OE}$ ) and both chip enables ( $\overline{CE1}$ , CE2), with write enable ( $\overline{WE}$ ) high. The chip drives I/O pins with the data word referenced by the input address. When either chip enable or output enable is inactive, or write enable is active, output drivers stay in high-impedance mode.

#### **Absolute maximum ratings**

Parameter	Symbol	Min	Max	Unit
Voltage on V <sub>CC</sub> relative to GND	V <sub>t1</sub>	-0.50	+5.0	V
Voltage on any pin relative to GND	V <sub>t2</sub>	-0.50	V <sub>CC</sub> +0.50	V
Power dissipation	P <sub>D</sub>	_	1.0	W
Storage temperature (plastic)	T <sub>stg</sub>	-65	+150	°C
Ambient temperature with V <sub>CC</sub> applied	T <sub>bias</sub>	-55	+125	°C
DC current into outputs (low)	I <sub>OUT</sub>	-	20	mA

Note: Stresses greater than those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

#### **Truth table**

CE1	CE2	WE	OE	Data	Mode
Н	Х	Х	Х	High Z	Standby (I <sub>SB</sub> , I <sub>SB1</sub> )
Х	L	Х	Х	High Z	Standby (I <sub>SB</sub> , I <sub>SB1</sub> )
L	Н	Н	Н	High Z	Output disable (I <sub>CC</sub> )
L	Н	Н	L	D <sub>OUT</sub>	Read (I <sub>CC</sub> )
L	Н	L	Х	D <sub>IN</sub>	Write ( <sub>ICC</sub> )

Key: X = don't care, L = low, H = high

### **Recommended operating conditions**

Parameter	Parameter			Nominal	Max	Unit
Supply voltage		V <sub>CC</sub>	3.0	3.3	3.6	V
Input voltage		V <sub>IH</sub>	2.0	—	$V_{CC} + 0.5$	V
		V <sub>IL</sub>	-0.5	—	0.8	V
Ambient operating temperature	commercial	T <sub>A</sub>	0	_	70	°C

ß

 $V_{IL}$  = -1.0V for pulse width less than 5ns  $V_{IH} = V_{CC}$  + 1.5V for pulse width less than 5ns

### DC operating characteristics (over the operating range) $^{1}$

			-]	10	-1	2	-1	15	-20		Unit
Parameter	Sym	Test conditions	Min	Max	Min	Max	Min	Max	Min	Max	Cint
Input leakage current	$ I_{LI} $	$V_{CC}$ = Max, $V_{IN}$ = GND to $V_{CC}$	_	1	-	1	_	1	-	1	μΑ
Output leakage current	I <sub>LO</sub>	$V_{CC} = Max, \overline{CE1} = V_{IH} \text{ or}$ $CE2 = V_{IL}, V_{OUT} = GND \text{ to } V_{CC}$	_	1	Ι	1	_	1	Ι	1	μΑ
Operating power supply current	I <sub>CC</sub>	$\begin{split} V_{CC} &= Max, \ \overline{CE1} \leq V_{IL}, \\ CE2 \geq V_{IH}, \ f = f_{Max}, \\ I_{OUT} &= 0 \ mA \end{split}$	_	70	l	65	_	60	Ι	55	mA
	I <sub>SB</sub>	$\label{eq:VCC} \begin{split} V_{CC} &= Max, \overline{CE1} \geq V_{IH} \text{ and/or} \\ CE2 \leq V_{IL},  f = f_{Max} \end{split}$	-	30	-	25	_	20	-	20	
Standby power supply current	I <sub>SB1</sub>	$\begin{split} V_{CC} &= Max, \ \overline{CE1} \geq V_{CC} - 0.2V \ and/\\ & \text{or } CE2 \leq 0.2V \\ & V_{IN} \leq 0.2V \ or \\ & V_{IN} \geq V_{CC} - 0.2V, \ f = 0 \end{split}$	_	5	_	5	_	5	_	5	mA
Output voltage	V <sub>OL</sub>	$I_{OL} = 8 \text{ mA}, V_{CC} = Min$	_	0.4	-	0.4	_	0.4	-	0.4	V
- uput forage	V <sub>OH</sub>	$I_{OH} = -4 \text{ mA}, V_{CC} = \text{Min}$	2.4	-	2.4	-	2.4	-	2.4	-	V

# Capacitance (f = 1 MHz, $T_a = 25 \text{ °C}$ , $V_{CC} = \text{NOMINAL})^2$

Parameter	Symbol	Signals	Test conditions	Max	Unit
Input capacitance	C <sub>IN</sub>	A, $\overline{\text{CE1}}$ , $\overline{\text{CE2}}$ , $\overline{\text{WE}}$ , $\overline{\text{OE}}$	$V_{IN} = 0V$	5	pF
I/O capacitance	C <sub>I/O</sub>	I/O	$V_{IN} = V_{OUT} = 0V$	7	pF

# Read cycle (over the operating range)<sup>3,9,12</sup>

		-1	-10		12	-1	15	-20			
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Notes
Read cycle time	t <sub>RC</sub>	10	-	12	-	15	-	20		ns	
Address access time	t <sub>AA</sub>	-	10	-	12	-	15	-	20	ns	3
Chip enable $(\overline{CE1})$ access time	t <sub>ACE1</sub>	-	10	-	12	-	15	-	20	ns	3, 12
Chip enable (CE2) access time	t <sub>ACE2</sub>	-	10	-	12	-	15	-	20	ns	3, 12
Output enable $(\overline{OE})$ access time	t <sub>OE</sub>	-	5	-	6	-	7	-	8	ns	
Output hold from address change	t <sub>OH</sub>	3	-	3	-	3	-	3	-	ns	5
$\overline{\text{CE1}}$ low to output in low Z	t <sub>CLZ1</sub>	3	-	3	-	3	-	3	-	ns	4, 5, 12
CE2 high to output in low Z	t <sub>CLZ2</sub>	3	-	3	-	3	-	3	-	ns	4, 5, 12
CE1 high to output in high Z	t <sub>CHZ1</sub>	-	3	-	3	-	4	-	5	ns	4, 5, 12
CE2 low to output in high Z	t <sub>CHZ2</sub>	-	3	-	3	-	4	-	5	ns	4, 5, 12
OE low to output in low Z	t <sub>OLZ</sub>	0	-	0	-	0	-	0	-	ns	4, 5
OE high to output in high Z	t <sub>OHZ</sub>	-	5	-	6	-	7	-	8	ns	4, 5
Power up time	t <sub>PU</sub>	0	—	0	-	0	-	0	-	ns	4, 5, 12
Power down time	t <sub>PD</sub>	I	10	-	12	-	15	1	20	ns	4, 5, 12

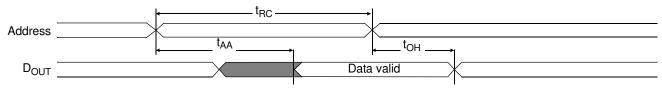
### Key to switching waveforms

Rising input

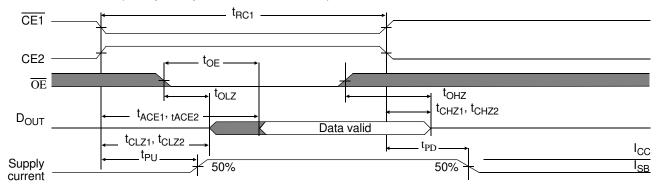
— Falling input

Undefined / don't care

# Read waveform 1 (address controlled)<sup>3,6,7,9,12</sup>



# Read waveform 2 (CE1, CE2, and OE controlled)<sup>3,6,8,9,12</sup>

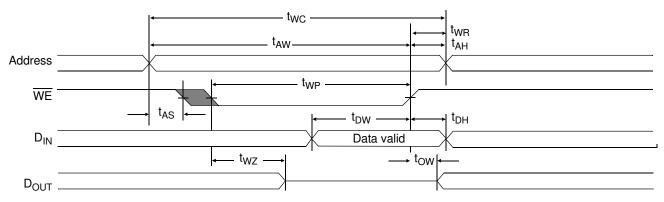


# Write cycle (over the operating range)<sup>11, 12</sup>

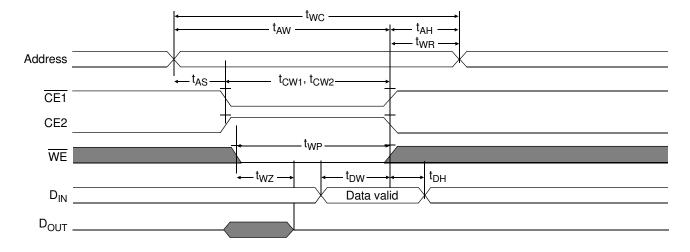
		-1	10	-1	12	-1	15	-2	20		
Parameter	Symbol	Min	Max	Min	Max	Min	Max	Min	Max	Unit	Notes
Write cycle time	t <sub>WC</sub>	10	-	12	-	15	-	20	-	ns	
Chip enable $(\overline{CE1})$ to write end	t <sub>CW1</sub>	8	—	9	-	10	-	12	-	ns	12
Chip enable (CE2) to write end	t <sub>CW2</sub>	8	—	9	-	10	—	12	-	ns	12
Address setup to write end	t <sub>AW</sub>	8	—	9	-	10	-	12	-	ns	
Address setup time	t <sub>AS</sub>	0	—	0	-	0	-	0	-	ns	12
Write pulse width	t <sub>WP</sub>	7	—	8	-	9	-	12	-	ns	
Write recovery time	t <sub>WR</sub>	0	—	0	-	0	-	0	-	ns	
Address hold from end of write	t <sub>AH</sub>	0	—	0	-	0	-	0	-	ns	
Data valid to write end	t <sub>DW</sub>	5	—	6	-	8	-	10	-	ns	
Data hold time	t <sub>DH</sub>	0	—	0	-	0	-	0	-	ns	4, 5
Write enable to output in high Z	t <sub>WZ</sub>	-	5		6	-	7		8	ns	4, 5
Output active from write end	t <sub>OW</sub>	1	—	1	-	1	—	1	-	ns	4, 5

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# Write waveform 1 (WE controlled)<sup>10,11,12</sup>



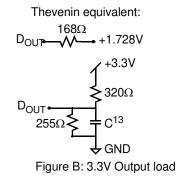
# Write waveform 2 (CE1 and CE2 controlled)<sup>10,11,12</sup>



#### **AC test conditions**

- Output load: see Figure B.
- Input pulse level: GND to 3.0V. See Figure A.
- Input rise and fall times: 2 ns. See Figure A.
- Input and output timing reference levels: 1.5V.

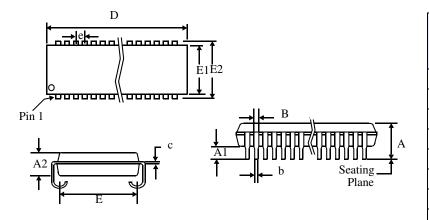




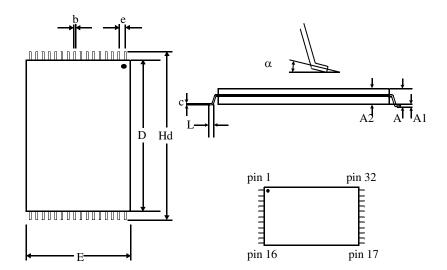
#### Notes

- 1 During  $V_{CC}$  power-up, a pull-up resistor to  $V_{CC}$  on  $\overline{CE1}$  is required to meet  $I_{SB}$  specification.
- 2 This parameter is sampled and not 100% tested.
- 3 For test conditions, see *AC Test Conditions*, Figures A, and B.
- 4  $t_{CLZ}$  and  $t_{CHZ}$  are specified with CL = 5pF, as in Figure C. Transition is measured ±500 mV from steady-state voltage.
- 5 This parameter is guaranteed, but not 100% tested.
- $\overline{\text{WE}}$  is high for read cycle.
- 7  $\overline{\text{CE1}}$  and  $\overline{\text{OE}}$  are low and CE2 is high for read cycle.
- 8 Address valid prior to or coincident with  $\overline{\text{CE1}}$  transition Low.
- 9 All read cycle timings are referenced from the last valid address to the first transitioning address.
- 10 N/A
- 11 All write cycle timings are referenced from the last valid address to the first transitioning address.
- 12  $\overline{\text{CE1}}$  and CE2 have identical timing.
- 13 C = 30 pF, except all high Z and low Z parameters where C = 5 pF.
- 14 N/A

# Package dimensions



	32-pin S m		32-pin S m		
	Min	Max	Min	Max	
А	0.128	0.145	0.132	0.146	
A1	0.025	-	0.025	-	
A2	0.095	0.105	0.105	0.115	
В	0.026	0.032	0.026	0.032	
b	0.016	0.020	0.015	0.020	
c	0.007	0.010	0.007	0.013	
D	0.820	0.830	0.820	0.830	
Е	0.255	0.275	0.354	0.378	
E1	0.295	0.305	0.395	0.405	
E2	0.330	0.340	0.435	0.445	
e	0.050	BSC	0.050 BSC		



	32-pin TSO	P 8×20 mm
	Min	Max
А	_	1.20
A1	0.05	0.15
A2	0.95	1.05
b	0.17	0.27
с	0.10	0.21
D	18.30	18.50
e	0.50 ne	ominal
E	7.90	8.10
Hd	19.80	20.20
L	0.50	0.70
α	0°	5°



# **Ordering codes**

Package \ Access time	Temp	<b>10 ns</b>	<b>12 ns</b>	15 ns	20 ns
Plastic SOJ, 300 mil	Commercial	AS7C31024B-10TJC	AS7C31024B-12TJC	AS7C31024B-15TJC	AS7C31024B-20TJC
Plastic SOJ, 400 mil	Commercial	AS7C31024B-10JC	AS7C31024B-12JC	AS7C31024B-15JC	AS7C31024B-20JC
TSOP1 8×20 mm	Commercial	AS7C31024B-10TC	AS7C31024B-12TC	AS7C31024B-15TC	AS7C31024B-20TC
sTSOP1 8 x 13.4mm	Commercial	AS7C31024B-10STC	AS7C31024B-12STC	AS7C31024B-15STC	AS7C31024B-20STC

Note:

Add suffix 'N' to the above part number for lead free parts (Ex. AS7C31024B-10TJCN)

### Part numbering system

AS7C	X	1024B	-XX	X	X	X
SRAM prefix	3 = 3.3 V CMOS	Device number	Access time	Package: $T = TSOP1 8 \times 20 \text{ mm}$ $ST = sTSOP1 8 \times 13.4 \text{ mm}$ J = SOJ 400  mil TJ = SOJ 300  mil	Temperature range C = Commercial, 0° C to 70° C	N=Lead Free Part



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